Vishay Semiconductors

Fast Recovery Diodes (Stud Version), 6 A, 12 A



PRODUCT SUMMARY	
I _{F(AV)}	6 A, 12 A
Package	DO-203AA (DO-4)
Circuit configuration	Single diode

FEATURES

- Short reverse recovery time
- · Low stored charge
- · Wide current range
- Excellent surge capabilities
- Standard JEDEC[®] types
- · Stud cathode and stud anode versions
- Fully characterized reverse recovery conditions
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC power supplies
- Inverters
- Converters
- Choppers
- Ultrasonic systems
- Freewheeling diodes

MAJOR RAT	MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
1		6 ⁽¹⁾	12 ⁽¹⁾	Α	
I _{F(AV)}	T _C maximum	100	100	°C	
I _{F(RMS)}		9.5	19	Α	
1	50 Hz	72	145	А	
I _{FSM}	60 Hz	75 ⁽¹⁾	150 ⁽¹⁾	A	
l ² t	50 Hz	26	103	A ² s	
1-1	60 Hz	23	94	A-5	
I ² √t		363	856	l²√s	
V _{RRM}	Range	50 to 400 ⁽¹⁾	50 to 400 ⁽¹⁾	V	
t _{rr}		See Recovery Characteristics table	See Recovery Characteristics table	ns	
TJ	Range	-65 to +150	-65 to +150	°C	

Note

(1) JEDEC® registered values

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ELECTRICAL SPECIFICATIONS

VOLTAG	E RATING	S				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 25 °C μA	I _{RRM} MAXIMUM AT T _J = 100 °C mA	I _{RRM} MAXIMUM AT T _J = 150 °C mA
1N3879(R)		50	75			
1N3880(R)		100	150			
1N3881(R)	-	200	250	15 ⁽¹⁾	1.0 ⁽¹⁾	3.0 (1)
1N3882(R)		300	350			
1N3883(R)		400	450			
1N3889(R)		50	75			
1N3890(R)		100	150			
1N3891(R)	-	200	250	25 ⁽¹⁾	3.0 (1)	5.0 ⁽¹⁾
1N3892(R)		300	350			
1N3893(R)		400	450			

Note

(1) JEDEC® registered values

FORWARD CONDUCTION	DUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
Maximum average forward current		180° cond	uction, half sine	wave	6 ⁽¹⁾	12 ⁽¹⁾	Α
at case temperature	I _{F(AV)}	DC			100	100	°C
Maximum RMS current	I _{F(RMS)}				9.5	19	
		t = 10 ms	No voltage		85	170	
Maximum peak, one-cycle		t = 8.3 ms	t = 8.3 ms reapplied		90	180	Α
non-repetitive forward current	I _{FSM}	t = 10 ms	t = 10 ms 100 % V _{RRM}		72	145	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	75 ⁽¹⁾	150 ⁽¹⁾	
		t = 10 ms	No voltage	initial T _J = 150 °C	36	145	
Maying up 12t far fuging	l ² t	t = 8.3 ms		1J = 150 C	33	130	A ² s
Maximum I ² t for fusing	1-1	t = 10 ms			26	103	A-S
		t = 8.3 ms	reapplied		23	94	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms	t = 0.1 ms to 10 ms, no voltage reapplied		363	1452	A²√s
Marian and formal voltage due	V	T _J = 25 °C	; I _F = Rated I _{F(A'}	_{V)} (DC)	1.4 (1)	1.4 (1)	.,
Maximum forward voltage drop	V_{FM}	T _C = 100 °	C; $I_{FM} = \pi \times rate$	ed I _{F(AV)}	1.5 (1)	1.5 ⁽¹⁾	V

Note

(1) JEDEC® registered values

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RECOVERY CH	ARACTE	RISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
Maximum reverse	+	$T_J = 25 ^{\circ}\text{C}$, $I_F = 1 \text{A to V}_R = 30 \text{V}$, $dI_F/dt = 100 \text{A/}\mu\text{s}$	150	150	ne	
recovery time	t _{rr}	$T_J = 25$ °C, $dI_F/dt = 25$ A/ μ s, $I_{FM} = \pi$ x rated $I_{F(AV)}$	300 ⁽¹⁾	300 ⁽¹⁾	ns	· •
Maximum peak recovery current	I _{RM(REC)}	$I_{FM} = \pi x \text{ rated } I_{F(AV)}$	4 (1)	5 (1)	-	I _{FM}
		T_J = 25 °C, I_F = 1 A to V_R = 30 V, dI_F/dt = 100 A/ μ s	400	350		dir/dt Q _{rr}
Maximum reverse recovery charge	Q _{rr}	T_J = 25 °C, dI_F/dt = 25 A/ μ s, I_{FM} = π x rated $I_{F(AV)}$	400	400	nC	I _{RM(REC)}

Note

(1) JEDEC® registered values

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
Maximum junction operating temperature range	TJ		-65 to	+150	°C	
Maximum storage temperature range	T _{Stg}		-65 to	+175		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	2.0	9000	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5		- °C/W	
Allowable mounting torque		Not lubricated threads) - 10 % 3)	N·m	
Allowable mounting torque		Lubricated threads	1.2 + 0 - 10 % (10)		(lbf · in)	
Approximate weight				7	g	
Approximate weight			0.	25	oz.	
Case style		JEDEC®	DC)-203AA (DO-4)		

∆R _{thJC} CONDUCTI	ON					
CONDUCTION ANGLE	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	TEST CONDITIONS	UNITS
	SINUSOIDAL	CONDUCTION	RECTANGULAR	CONDUCTION		
180°	0.58	0.46	0.33	0.26	T _{.1} = 150 °C	
120°	0.60	0.48	0.58	0.46		K/W
60°	1.28	1.02	1.28	1.02	1) = 150 C	rv vv
30°	2.20	1.76	2.20	1.76		

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

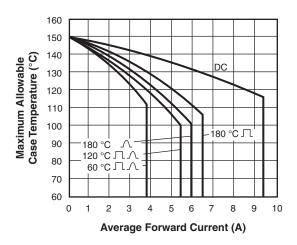


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N3879 Series

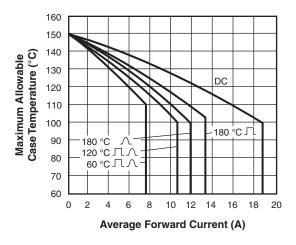
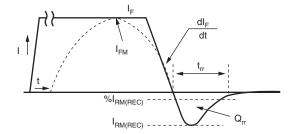


Fig. 2 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N3889 Series



 $\mathbf{I}_{\mathrm{F}},\,\mathbf{I}_{\mathrm{FM}}$ - Peak forward current prior to commutation

-dl_F/dt - Rate of fall of forward current

 $I_{RM(REC)}$ - Peak reverse recovery current t_{rr} - Reverse recovery time

Q_{rr} - Reverse recovered charge

Fig. 3 - Reverse Recovery Time Test Waveform

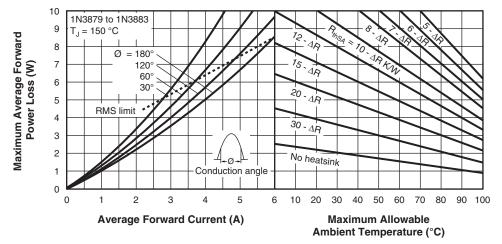
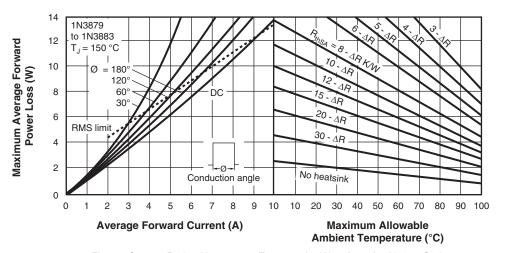


Fig. 4 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3879 Series	Fig. 4 - Current Rating	Nomogram	(Sinusoidal	Waveforms).	1N3879 Series
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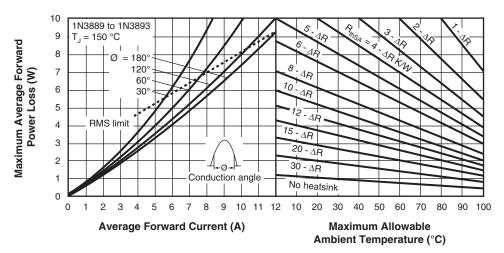
Conduction angle - Ø	∆R - K/W
180°	0.58
120°	0.60
60°	1.28
30°	2.20





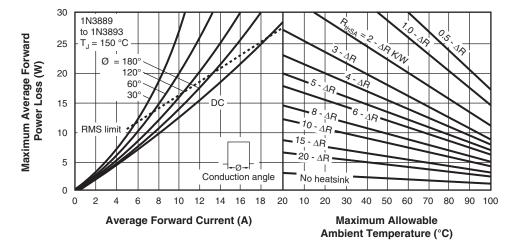
Conduction angle - Ø	∆R - K/W
DC	0
180°	0.33
120°	0.58
60°	1.28
30°	2.20

Fig. 5 - Current Rating Nomogram (Rectangular Waveforms), 1N3879 Series



Conduction angle - Ø	ΔR - KW
180°	0.46
120°	0.48
60°	1.02
30°	1.76

Fig. 6 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3889 Series



Conduction angle - Ø	∆R - K/W
DC	0
180°	0.26
120°	0.46
60°	1.02
30°	1.76

Fig. 7 - Current Rating Nomogram (Rectangular Waveforms), 1N3889 Series

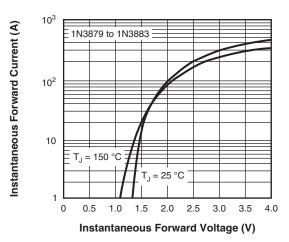


Fig. 8 - Maximum Forward Voltage vs. Forward Current, 1N3879 Series

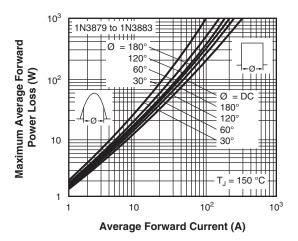


Fig. 9 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N3879 Series

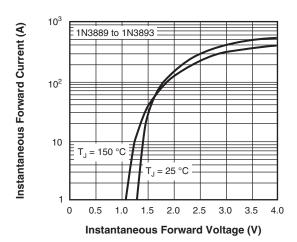


Fig. 10 - Maximum Forward Voltage vs. Forward Current, 1N3889 Series

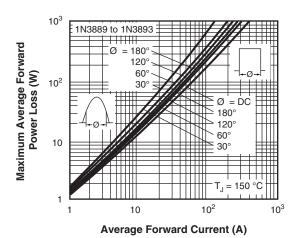


Fig. 11 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N3889 Series

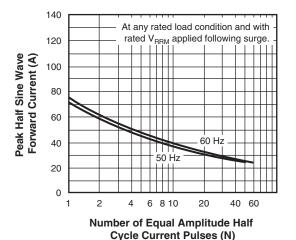
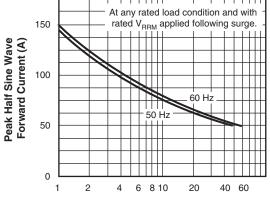


Fig. 12 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N3879 Series



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 13 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N3889 Series

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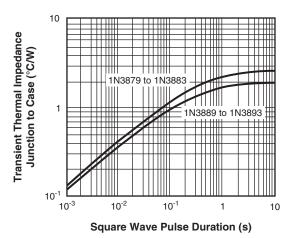


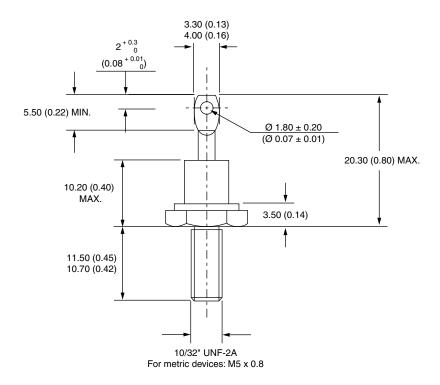
Fig. 14 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration, All Series

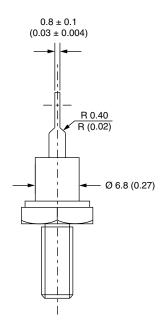
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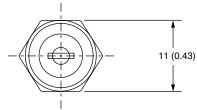


DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)









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